

# 100mA / 50V Digital transistors (with built-in resistors)

## DTC143EM / DTC143EE / DTC143EUA / DTC143EKA / DTC143ESA

### ●Applications

Inverter, Interface, Driver

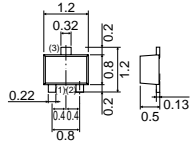
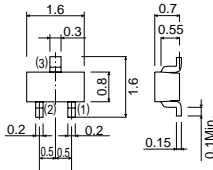
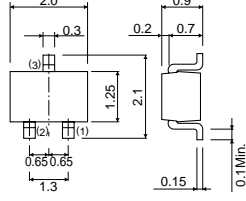
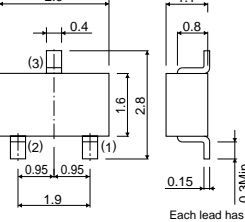
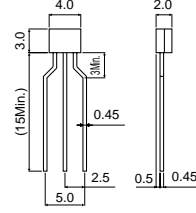
### ●Features

- 1) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
- 2) The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
- 3) Only the on/off conditions need to be set for operation, making the device design easy.

### ●Structure

NPN epitaxial planar silicon transistor (Resistor built-in type)

### ●External dimensions (Unit : mm)

<p>DTC143EM</p>  <p>ROHM : VMT3</p> <p>Abbreviated symbol : 23</p> <p>(1) IN (2) GND (3) OUT</p>	<p>DTC143EE</p>  <p>ROHM : EMT3</p> <p>Abbreviated symbol : 23</p> <p>(1) GND (2) IN (3) OUT</p>
<p>DTC143EUA</p>  <p>ROHM : UMT3 EIAJ : SC-70</p> <p>Abbreviated symbol : 23</p> <p>(1) GND (2) IN (3) OUT</p>	<p>DTC143EKA</p>  <p>ROHM : SMT3 EIAJ : SC-59</p> <p>Abbreviated symbol : 23</p> <p>Each lead has same dimensions</p> <p>(1) GND (2) IN (3) OUT</p>
<p>DTC143ESA</p>  <p>ROHM : SPT EIAJ : SC-72</p> <p>Abbreviated symbol : C143ES</p> <p>(1) GND (2) OUT (3) IN</p>	

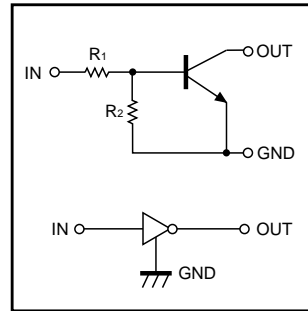
# DTC143EM / DTC143EE / DTC143EUA DTC143EKA / DTC143ESA

## Transistors

### ●Packaging specifications

Part No.	Package	VMT3	EMT3	UMT3	SMT3	SPT
	Package type	Taping	Taping	Taping	Taping	Taping
	Code	T2L	TL	T106	T146	TP
	Basic ordering unit (pieces)	8000	3000	3000	3000	5000
DTC143EM		○	-	-	-	-
DTC143EE		-	○	-	-	-
DTC143EUA		-	-	○	-	-
DTC143EKA		-	-	-	○	-
DTC143ESA		-	-	-	-	○

### ●Equivalent circuit



$R_1=R_2=4.7k\Omega$

### ●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits					Unit
		DTC143EM	DTC143EE	DTC143EUA	DTC143EKA	DTC143ESA	
Supply voltage	V <sub>CC</sub>	50					V
Input voltage	V <sub>IN</sub>	-10 to +30					V
Output current	I <sub>O</sub>	100					mA
	I <sub>C(Max.)</sub>	100					
Power dissipation	P <sub>D</sub>	150		200	300	mW	
Junction temperature	T <sub>J</sub>	150					°C
Storage temperature	T <sub>stg</sub>	-55 to +150					°C

### ●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Input voltage	V <sub>I(off)</sub>	-	-	0.5	V	V <sub>CC</sub> =5V, I <sub>O</sub> =100μA
	V <sub>I(on)</sub>	3	-	-		V <sub>O</sub> =0.3V, I <sub>O</sub> =20mA
Output voltage	V <sub>O(on)</sub>	-	0.1	0.3	V	I <sub>O</sub> /I <sub>I</sub> =10mA/0.5mA
Input current	I <sub>I</sub>	-	-	1.8	mA	V <sub>I</sub> =5V
Output current	I <sub>O(off)</sub>	-	-	0.5	μA	V <sub>CC</sub> =50V, V <sub>I</sub> =0V
DC current gain	G <sub>I</sub>	30	-	-	-	V <sub>O</sub> =5V, I <sub>O</sub> =10mA
Input resistance	R <sub>1</sub>	3.29	4.7	6.11	kΩ	-
Resistance ratio	R <sub>2</sub> /R <sub>1</sub>	0.8	1	1.2	-	-
Transition frequency	f <sub>T</sub> *	-	250	-	MHz	V <sub>CE</sub> =10V, I <sub>E</sub> =-5mA, f=100MHz

\* Characteristics of built-in transistor

Transistors

● Electrical characteristic curves

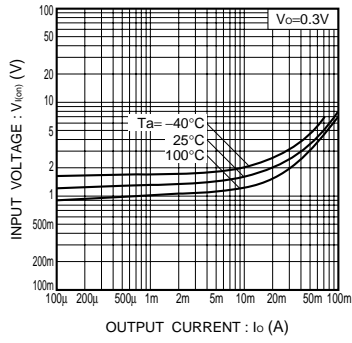


Fig.1 Input voltage vs. output current (ON characteristics)

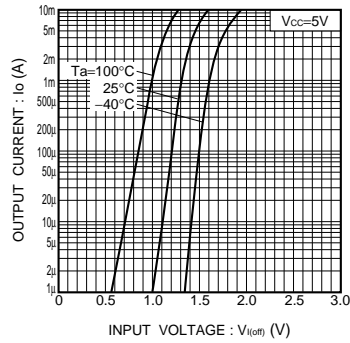


Fig.2 Output current vs. input voltage (OFF characteristics)

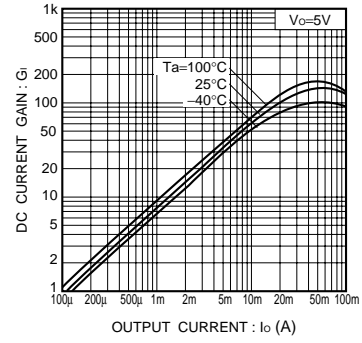


Fig.3 DC current gain vs. output current

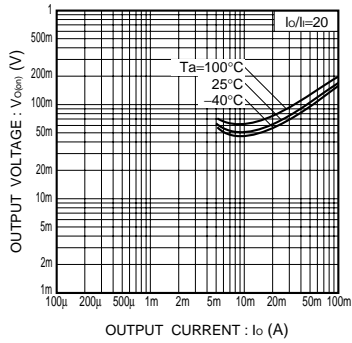


Fig.4 Output voltage vs. output current

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